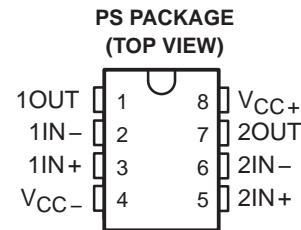


- Wide Range of Supply Voltages; Single Supply . . . 3 V to 36 V, or Dual Supplies
- Class AB Output Stage
- High-Impedance N-Channel-JFET Input Stage . . . $10^{12} \Omega$ Typ
- Internal Frequency Compensation
- Short-Circuit Protection
- Input Common Mode Includes V_{CC-}
- Low Input Offset Current . . . 50 pA
- Low Input Bias Current . . . 200 pA Typ



description

The TL092 JFET-input operational amplifier is similar in performance to the MC3403 family, but with much higher input impedance derived from a FET input stage. The N-channel-JFET input stage allows a common-mode input voltage range that includes the negative supply voltage and offers a typical input impedance of $10^{12} \Omega$, a typical input offset current of 50 pA, and a typical input bias current of 200 pA. This device is designed to operate from a single supply over a range of 3 V to 36 V. Operation from split supplies also is possible, provided the difference between the two supplies is 3 V to 36 V. Output voltage range is from V_{CC-} to $V_{CC+} - 1.3$ V, with a load resistor to V_{CC-} .

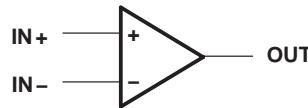
The TL092 is characterized for operation from 0°C to 70°C.

AVAILABLE OPTIONS

TA	PACKAGED DEVICE
	PLASTIC SMALL OUTLINE (PS)
0°C to 70°C	TL092CPSR

The PS package is only available taped and reeled. Add the suffix R to device type for ordering (e.g., TL092CPSR).

symbol

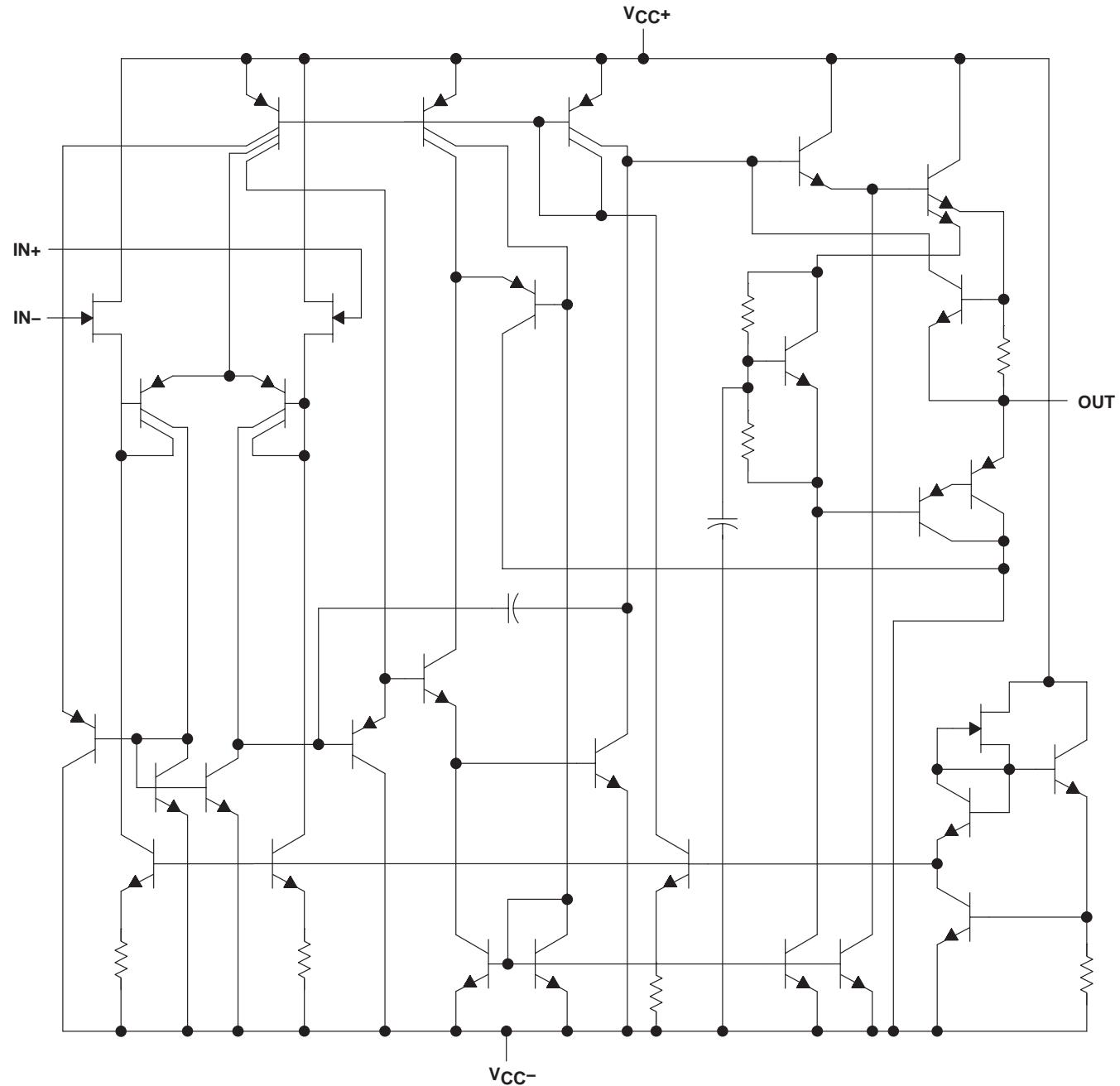


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TL092 DUAL JFET-INPUT OPERATIONAL AMPLIFIER

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schematic



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage: V_{CC+} (see Note 1)	18 V
V_{CC-} (see Note 1)	-18 V
V_{CC+} with respect to V_{CC-}	36 V
Differential input voltage, V_{ID} (see Note 2)	±36 V
Input voltage, V_I (see Notes 1 and 3)	±18 V
Package thermal impedance, θ_{JA} (see Notes 4 and 5)	95°C/W
Lead temperature 1.6 mm (1/16 inch) from case for 10 seconds	260°C
Storage temperature range, T_{stg}	-65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-} .
2. Differential voltages are at the noninverting input with respect to the inverting input.
3. Neither input must ever be more positive than V_{CC+} or more negative than $V_{CC-} - 0.3$ V.
4. Maximum power dissipation is a function of T_J (max), θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(\text{max}) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can impact reliability.
5. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions

		MIN	MAX	UNIT
$V_{CC\pm}$	Supply voltage	3	36	V
T_A	Operating free-air temperature range	0	70	°C

TL092

DUAL JFET-INPUT OPERATIONAL AMPLIFIER

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**electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V
(all characteristics are specified under open-loop conditions, unless otherwise noted)**

PARAMETER	TEST CONDITIONS	T_A	MIN	TYP†	MAX	UNIT
V_{IO} Input offset voltage	$R_S = 50 \Omega$	25°C	5	15		mV
		Full range			20	
αV_{IO} Temperature coefficient of input offset voltage		25°C	10			$\mu V/^\circ C$
I_{IO}^\ddagger Input offset current		25°C	50	200	pA	pA
		Full range		5	nA	
I_{IB}^\ddagger Input bias current		25°C	200	400	pA	pA
		Full range		10	nA	
V_{ICR} Common-mode input voltage range		25°C	V_{CC-} to 12	V_{CC-} to 13		V
$V_{O(PP)}$ Peak output voltage swing	$R_L = 2 \text{ k}\Omega$	25°C	± 10	± 13		V
	$R_L = 10 \text{ k}\Omega$	25°C	± 12	± 13.5		
	$R_L = 2 \text{ k}\Omega$	Full range	± 10			
AVD Large-signal differential voltage amplification	$R_L = 2 \text{ k}\Omega, V_O = \pm 10 \text{ V}$	25°C	20	200		V/mV
		Full range		15		
B_{OM} Maximum output swing bandwidth	$R_L = 2 \text{ k}\Omega, V_{O(PP)} = 20 \text{ V}, THD < 5\%$	25°C	9			kHz
B_1 Unity gain bandwidth	$R_L = 10 \text{ k}\Omega, V_O = 50 \text{ mV}$	25°C	1			MHz
ϕ_m Phase margin	$R_L = 2 \text{ k}\Omega, C_L = 200 \text{ pF}$	25°C	60°			
r_i Input resistance	$f = 20 \text{ Hz}$	25°C	10^{12}			Ω
r_o Output resistance	$f = 20 \text{ Hz}$	25°C	75			Ω
CMRR Common-mode rejection ratio	$R_S = 50 \Omega, V_{IC} = V_{ICR}$	25°C	70	90		dB
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC}/\Delta V_{IO}$)	$R_S = 50 \Omega, V_{CC\pm} = \pm 3 \text{ V to } \pm 15 \text{ V}$	25°C	75	90		dB
I_{OS} Short-circuit output current		25°C	40			mA
I_{CC} Supply current (per amplifier)	$V_O = 0, \text{ No load}$	25°C	1.5	2.5		mA

† All typical values are at $T_A = 25^\circ C$.

‡ Input bias currents of a FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive. Pulse techniques that maintain the junction temperature as close to the ambient temperature as possible must be used.

electrical characteristics at specified free-air temperature, $V_{CC+} = 5 \text{ V}$, $V_{CC-} = 0 \text{ V}$, $T_A = 25^\circ C$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
V_{IO} Input offset voltage	$R_S = 50 \Omega, V_O = 2.5 \text{ V}$		5	15	mV
I_{IO} Input offset current	$V_O = 2.5 \text{ V}$		50	200	pA
I_{IB} Input bias current	$V_O = 2.5 \text{ V}$		200	400	pA
$V_{O(PP)}$ Peak output voltage swing	$R_L = 10 \text{ k}\Omega$		3.3	3.5	V
	$R_L = 10 \text{ k}\Omega, V_{CC+} = 5 \text{ V to } 30 \text{ V}$	$V_{CC+} - 1.7$			V
AVD Large-signal differential voltage amplification	$R_L = 2 \text{ k}\Omega, \Delta V_O = 1.6 \text{ V}$	20	200		V/mV
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC}/\Delta V_{IO}$)	$R_S = 50 \Omega, V_{CC\pm} = \pm 3 \text{ V to } \pm 15 \text{ V}$	75			dB
I_{CC} Supply current (per amplifier)	$V_O = 2.5 \text{ V}, \text{ No load}$		1.5	2.5	mA
V_{O1}/V_{O2} Channel separation	$f = 1 \text{ kHz to } 20 \text{ kHz}$		120		dB

† All typical values are at $T_A = 25^\circ C$.



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operating characteristics, $V_{CC\pm} = \pm 15$ V, $T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR	$V_I = \pm 10$ V (see Figure 1), $C_L = 100$ pF, $R_L = 2$ k Ω		0.6		V/ μ s
t_r	$\Delta V_O = 50$ mV (see Figure 1), $C_L = 100$ pF, $R_L = 2$ k Ω		0.2		μ s
t_f	$\Delta V_O = 50$ mV (see Figure 1), $C_L = 100$ pF, $R_L = 2$ k Ω		0.2		μ s
Overshoot factor	$\Delta V_O = 50$ mV (see Figure 1), $C_L = 100$ pF, $R_L = 2$ k Ω		20%		
Crossover distortion	$V_{IPP} = 30$ mV, $V_O(PP) = 2$ V, $f = 10$ kHz		1%		
V_n	$R_S = 100$ Ω , $f = 1$ kHz	34			nV/ $\sqrt{\text{Hz}}$

PARAMETER MEASUREMENT INFORMATION

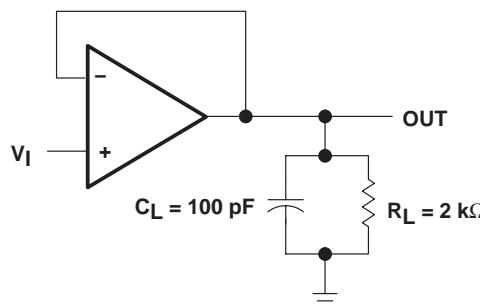


Figure 1. Unity-Gain Amplifier

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TL092CPSR	ACTIVE	SO	PS	8		Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL092CPSRE4	ACTIVE	SO	PS	8		Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

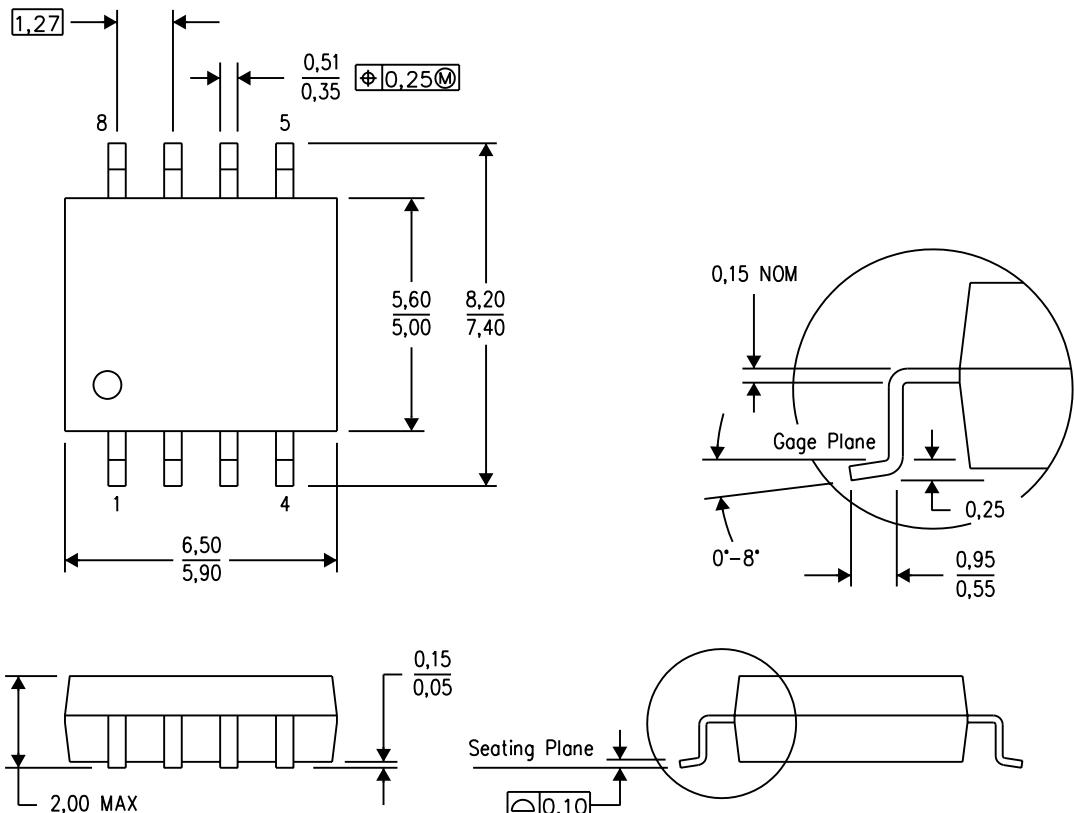
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MECHANICAL DATA

PS (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



4040063/C 03/03

NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

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